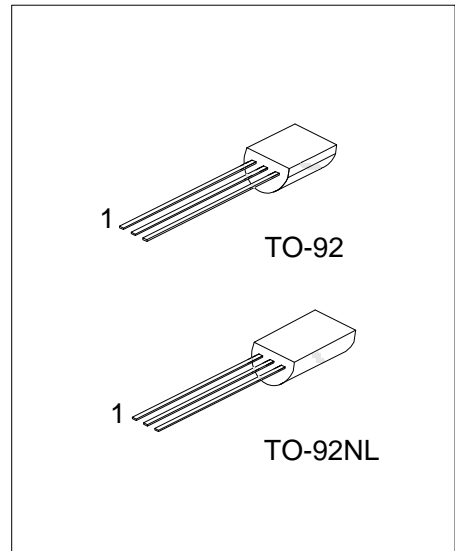




HE8551

PNP SILICON TRANSISTOR

LOW VOLTAGE HIGH
CURRENT SMALL SIGNAL
PNP TRANSISTOR



DESCRIPTION

The UTC **HE8551** is a low voltage high current small signal PNP transistor, designed for Class B push-pull 2W audio amplifier for portable radio and general purpose applications.

FEATURES

- * Collector current up to 1.5A
- * Collector-emitter voltage up to 25 V
- * Complimentary to UTC **HE8051**

ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
HE8551L-x-T92-B	HE8551G-x-T92-B	TO-92	E	B	C	Tape Box
HE8551L-x-T92-K	HE8551G-x-T92-K	TO-92	E	B	C	Bulk
HE8551L-x-T92-R	HE8551G-x-T92-R	TO-92	E	B	C	Tape Reel
HE8551L-x-T9N-B	HE8551G-x-T9N-B	TO-92NL	E	B	C	Tape Box
HE8551L-x-T9N-K	HE8551G-x-T9N-K	TO-92NL	E	B	C	Bulk
HE8551L-x-T9N-R	HE8551G-x-T9N-R	TO-92NL	E	B	C	Tape Reel

<p>HE8551L-x-T92-B</p> <p>(1)Packing Type (2)Package Type (3)Rank (4)Lead Free</p>	<p>(1) B: Tape Box, K: Bulk, R: Tape Reel (2) T92: TO-92, T9N: TO-92NL (3) x: refer to Classification of h_{FE2} (4) G: Halogen Free, L: Lead Free</p>
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■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	-40	V
Collector-Emitter Voltage		V_{CEO}	-25	V
Emitter-Base Voltage		V_{EBO}	-6	V
Collector Dissipation ($T_A=25^\circ\text{C}$)	TO-92	P_c	0.625	W
	TO-92NL		0.9	
Collector Current		I_c	-1.5	A
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-65 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

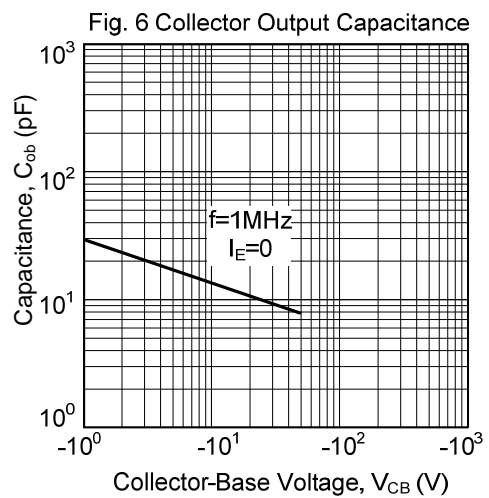
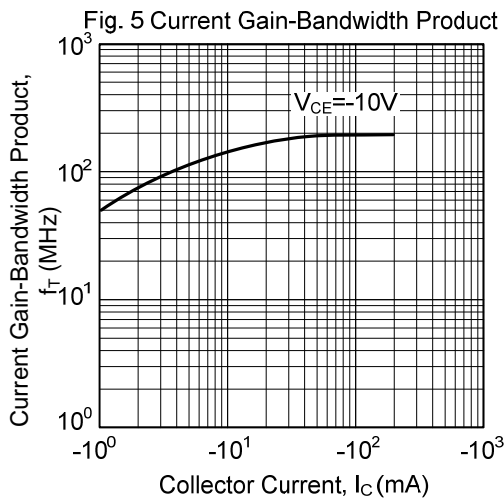
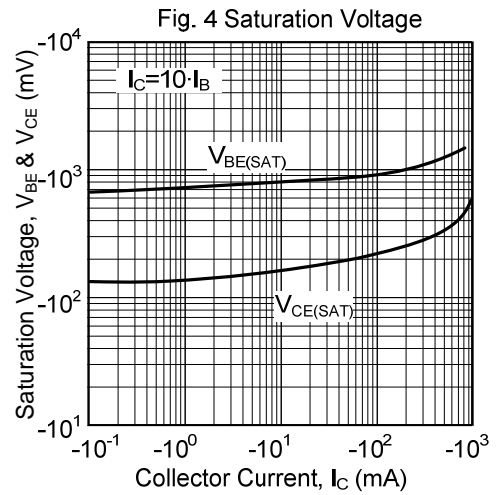
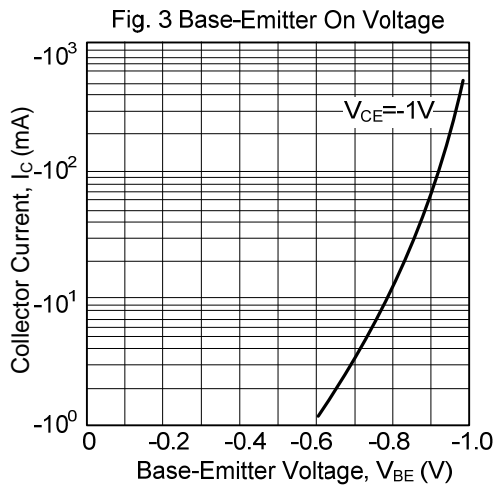
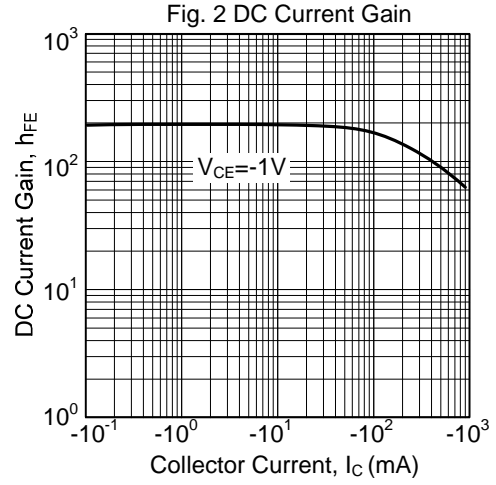
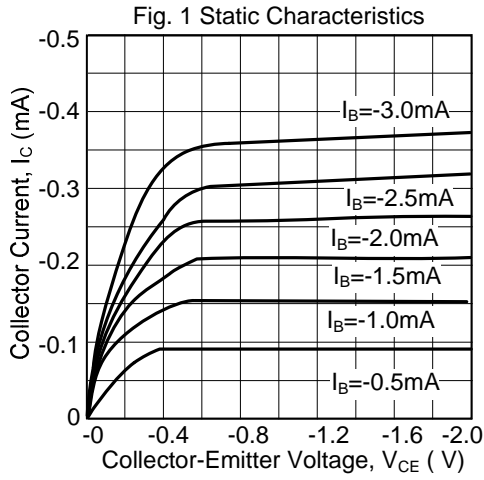
■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=-100\mu\text{A}$, $I_E=0$	-40			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=-2\text{mA}$, $I_B=0$	-25			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E=-100\mu\text{A}$, $I_C=0$	-6			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-35\text{V}$, $I_E=0$			-100	nA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-6\text{V}$, $I_C=0$			-100	nA
DC Current Gain	h_{FE1}	$V_{CE}=-1\text{V}$, $I_C=-5\text{mA}$	45	170		
	h_{FE2}	$V_{CE}=-1\text{V}$, $I_C=-100\text{mA}$	85	160	500	
	h_{FE3}	$V_{CE}=-1\text{V}$, $I_C=-800\text{mA}$	40	80		
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=-800\text{mA}$, $I_B=-80\text{mA}$		-0.28	-0.5	V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=-800\text{mA}$, $I_B=-80\text{mA}$		-0.98	-1.2	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=-1\text{V}$, $I_C=-10\text{mA}$		-0.66	-1.0	V
Current Gain Bandwidth Product	f_T	$V_{CE}=-10\text{V}$, $I_C=-50\text{mA}$	100	190		MHz
Output Capacitance	C_{OB}	$V_{CB}=-10\text{V}$, $I_E=0$, $f=1\text{MHz}$		9.0		pF

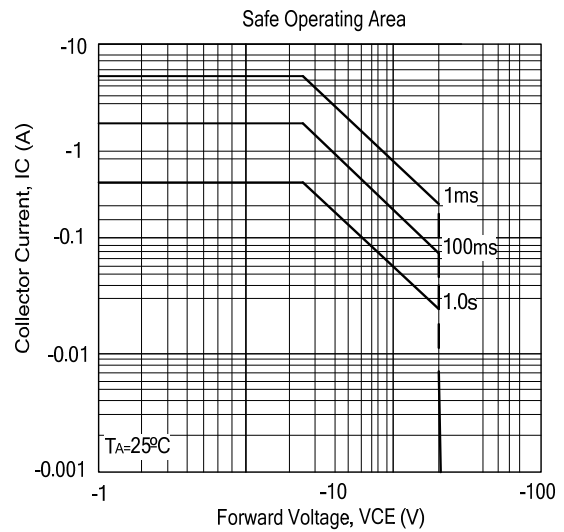
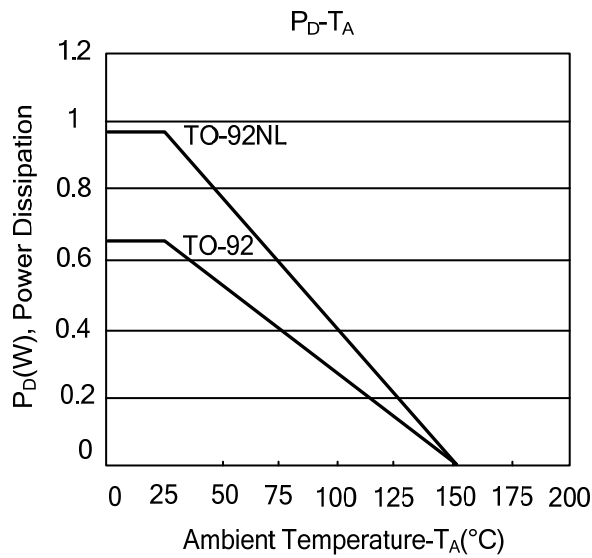
■ CLASSIFICATION OF h_{FE2}

RANK	C	D	E
RANGE	120-200	160-300	250-500

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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